

- 20 W Pulsed Power Dissipation
- 100 V Capability
- 2 A Continuous Collector Current
- 4 A Peak Collector Current
- Customer-Specified Selections Available

LP PACKAGE
(TOP VIEW)

MDTRAB

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	V _{CBO}	40	V
		60	
		80	
		100	
Collector-emitter voltage ($I_B = 0$)	V _{CEO}	40	V
		60	
		80	
		100	
Emitter-base voltage	V _{EBO}	5	V
Continuous collector current	I _C	2	A
Peak collector current (see Note 1)	I _{CM}	4	A
Continuous base current	I _B	1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P _{tot}	0.8	W
Pulsed power dissipation (see Note 3)	P _T	20	W
Operating junction temperature range	T _j	-55 to +150	°C
Storage temperature range	T _{stg}	-55 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds	T _L	260	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%$.
 2. Derate linearly to 150°C case temperature at the rate of 6.4 mW/°C.
 3. $V_{CE} = 20$ V, $I_C = 1$ A, $t_p = 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 5 \text{ mA}$ (see Note 4)	$I_B = 0$	TIPP31 TIPP31A TIPP31B TIPP31C	40 60 80 100			V
I_{CES} Collector-emitter cut-off current	$V_{CE} = 40 \text{ V}$ $V_{CE} = 60 \text{ V}$ $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIPP31 TIPP31A TIPP31B TIPP31C			0.2 0.2 0.2 0.2	mA
I_{CEO} Collector cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_B = 0$ $I_B = 0$	TIPP31/31A TIPP31B/31C			0.3 0.3	mA
I_{EBO} Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				1	mA
h_{FE} Forward current transfer ratio	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 1 \text{ A}$ $I_C = 2 \text{ A}$	(see Notes 4 and 5)	20 10			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 375 \text{ mA}$	$I_C = 2 \text{ A}$	(see Notes 4 and 5)			1	V
V_{BE} Base-emitter voltage	$V_{CE} = 4 \text{ V}$	$I_C = 2 \text{ A}$	(see Notes 4 and 5)			1.5	V
h_{fe} Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ kHz}$	20			
$ h_{fel} $ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$	3			

NOTES: 4. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

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